

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







ST3DV520A



High bandwidth switch with 20- to 10-bit MUX/DEMUX

Datasheet - production data

Features

■ Low R_{ON}: 4.0 Ω typical

■ V_{CC} operating range: 3.0 to 3.6 V

■ Enhanced ESD protection: > 8 kV (contact) and 15 kV (HBM)

■ Channel on capacitance: 9.5 pF typical

Switching time speed: 9 ns

Near to zero propagation delay: 250 ps
 Very low crosstalk: -45 dB at 250 MHz

■ Bit-to-bit skew: 200 ps

> 600 MHz -3 dB typical bandwidth (or data frequency)

Package: QFN56

Package: QFN56

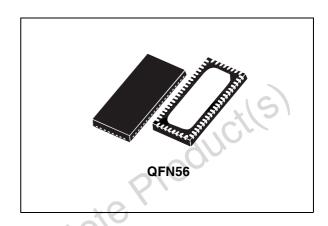


Table 1. Device summary

Order code	Package	Packing
ST3DV520AQTR	QFN56	Tape and reel

Contents ST3DV520A

Contents

1	Description
2	Pin description4
3	Maximum ratings 6 Recommended operating conditions 6
4	Electrical characteristics
5	Package information
6	Revision history
005	Description

ST3DV520A Description

1 Description

The ST3DV520A 20- to 10-bit multiplexer/demultiplexer is a high bandwidth bidirectional switch with low R_{ON} suitable for analog video applications.

The signal from each input is multiplexed into one of two selected outputs, while the unselected switch goes into Hi-Z status. The device is designed for very low crosstalk, low bit-to-bit skew and low I/O capacitance.

The ST3DV520A supports high definition (HD) video switching standards and is also suitable for general-purpose switching that requires high signal integrity.

Pin description ST3DV520A

2 Pin description

Figure 1. Pin connection (top through view)

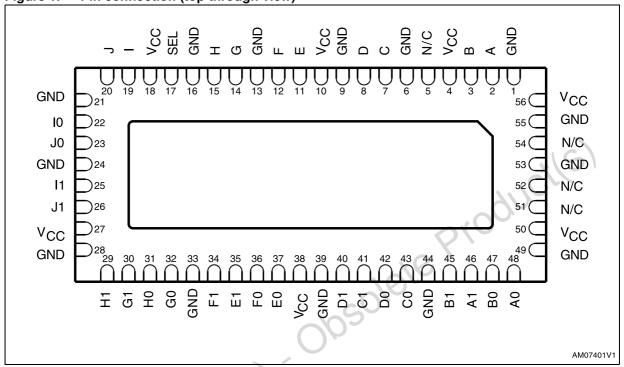


Table 2. Pin description

Pin	Symbol	Name and function
2, 3, 7, 8, 11, 12, 14, 15, 19, 20	A, B, C, D, E, F, G, H, I, J	10-bit bus
48, 47, 43, 42, 37, 36, 32, 31, 22, 23	A0, B0, C0, D0, E0, F0, G0, H0, I0, J0	10-bit multiplexed to bus 0
46, 45, 41, 40, 35, 34, 30, 29, 25, 26	A1, B1, C1, D1, E1, F1, G1, H1, I1, J1	10-bit multiplexed to bus 1
5, 51, 52, 54	N/C	Not connected
17	SEL	Bus and LED switch selection
4, 10, 18, 27, 38, 50, 56	V _{CC}	Supply voltage
1, 6, 9, 13, 16, 21, 24, 28, 33, 39, 44, 49, 53, 55	GND	Ground

ST3DV520A Pin description

Figure 2. Input equivalent circuit

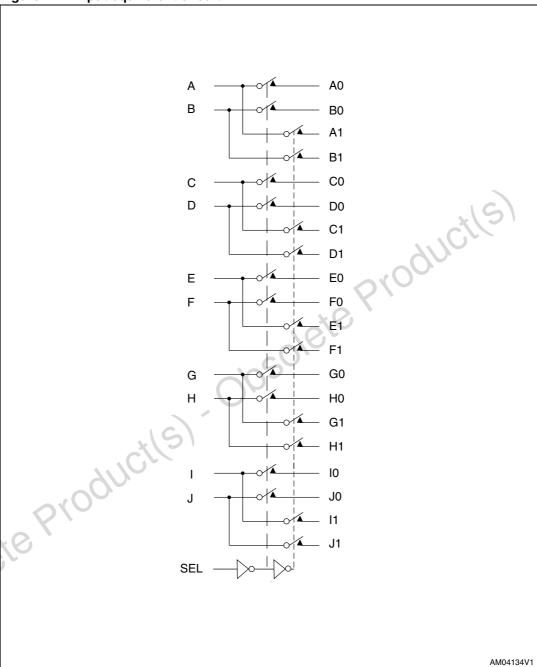


Table 3. Switch function table

SEL	Function
L	10-bit bus to 10-bit multiplexed bus 0
Н	10-bit bus to 10-bit multiplexed bus 1

Maximum ratings ST3DV520A

3 Maximum ratings

Stressing the device above the rating listed in *Table 4: Absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in *Table 5: Recommended operating conditions* of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage to ground	-0.5 to 4.6	V
V _{IO}	DC input output voltage	-0.5 to 4.6	٧
V _{IC}	DC control input voltage	-0.5 to 4.6	٧
I _O	DC output current ⁽¹⁾	120	mA
P _D	Power dissipation	0.5	W
T _{stg}	Storage temperature	-65 to 150	°C
TL	Lead temperature (10 sec.)	300	°C

^{1.} If V_{IO} x I_O does not exceed the maximum limit of P_D.

Recommended operating conditions

Table 5. Recommended operating conditions

	Symbol	Symbol Parameter -		Unit		
	Syllibol		Min.	Тур.	Max.	Offic
	V _{CC}	Supply voltage to ground	3	-	3.6	V
	V _{IC}	DC control input voltage (SEL)	0	_	5	V
7/6	V _{IO}	DC input/output voltage	0	_	V_{CC}	V
1050.	T_A	Operating temperature	-40	_	85	°C
Oh						

4 Electrical characteristics

Table 6. DC electrical characteristics ($V_{CC} = 3.3 \text{ V} \pm 10\%$)

Symbol	Parameter	Test condition	-40 to 85 °C			Unit
			Min.	Тур.	Max.	
V _{IH}	Voltage input high (SEL)	High level guaranteed	2	-	-	V
V _{IL}	Voltage input low (SEL)	Low level guaranteed	-0.5	-	0.8	V
V _{IK}	Clamp diode voltage (SEL)	V _{CC} = 3.6 V I _{IN} = -18 mA	-	-0.8	-1.2	V
I _{IH}	Input high current (SEL)	$V_{CC} = 3.6 \text{ V}$ $V_{IN} = V_{CC}$	-	947	±5	μА
I _{IL}	Input low current (SEL)	V _{CC} = 3.6 V V _{IN} = GND	57,0	_	±5	μΑ
l _{OFF(SW)} ⁽¹⁾	Leakage current through the switch common terminals (A to J)	$V_{CC} = 3.6 \text{ V}$ A to J = V_{CC} LED1 to LED3 = V_{CC} A0 to J0 = 0 V A1 to J1 = floating SEL = V_{CC}	-	-	±1	μА
I _{OFF(SEL)}	SEL pin leakage current	V _{CC} = 0 V SEL = 0 to 3.6 V	_	-	±1	μΑ
R _{ON}	Switch ON resistance ⁽²⁾	$V_{CC} = 3.0 \text{ V}$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -40 \text{ mA}$	_	4.0	6.5	Ω
R _{FLAT}	ON resistance flatness ⁽²⁾ , ⁽³⁾	V_{CC} = 3.0 V V_{IN} at 1.5 and V_{CC} I_{IN} = -40 mA	_	0.5	_	Ω
ΔR _{ON}	ON resistance match between channel $\Delta R_{ON} = R_{ONMAX} - R_{ONMIN}^{~(2)}, ^{(4)}$	$V_{CC} = 3.0 \text{ V}$ $V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -40 \text{ mA}$	_	0.4	1	Ω

^{1.} Refer to Figure 4: Test circuit for leakage current (I_{OFF}) on page 11.

Measured by voltage drop between channels at indicated current through the switch. ON resistance is determined by the lower of the voltages.

^{3.} Flatness is defined as the difference between the R_{ONMAX} and R_{ONMIN} of ON resistance over the specified range.

^{4.} ΔR_{ON} measured at same V_{CC} , temperature and voltage level.

Capacitance ($T_A = 25$ °C, f = 1 MHz) Table 7.

Symbol Parameter		Test condition		Unit		
Symbol	Farameter	rest condition	Min.	Тур.	Max.	Oill
C _{IN}	SEL pin input capacitance ⁽¹⁾	DC = 0.25 V AC = 0.5 V _{PP} f = 1 MHz	-	2	3	pF
C _{OFF}	Switch off capacitance ⁽²⁾	DC = 0.25 V AC = 0.5 V _{PP} f = 1 MHz	_	4	5	pF
C _{ON}	Switch on capacitance ⁽³⁾	DC = 0.25 V AC = 0.5 V _{PP} f = 1 MHz	_	9.5	11/5	pF

- 1. Refer to Figure 5 on page 11.
- 2. Refer to Figure 6 on page 12.
- 3. Refer to Figure 7 on page 12.

Table 8. **Power supply characteristics**

	capacitance.	f = 1 MHz			(C)	
1. Refer to F	igure 5 on page 11.			-0	O,	
2. Refer to F	2. Refer to Figure 6 on page 12.					
3. Refer to F	3. Refer to Figure 7 on page 12.					
Table 8.	Table 8. Power supply characteristics Value					
Symbol	Parameter	Test condition		-40 to 85 °C	:	Unit
Symbol	Parameter	Test condition	Min.	-40 to 85 °C Typ.	Max.	Unit

Dynamic electrical characteristics ($V_{CC} = 3.3 \text{ V} \pm 10\%$) Table 9.

010			-			
Symbol	Parameter	Test condition		-40 to 85 °C	;	Unit
-019			Min.	Тур.	Max.	•
X _{talk}	Crosstalk ⁽¹⁾	$R_L = 100 \Omega$ f = 250 MHz	-	-45	-	dB
O _{IRR}	Off isolation ⁽²⁾	$R_L = 100 \Omega$ f = 250 MHz	_	-37	_	dB
BW	-3 dB bandwidth ⁽³⁾	$R_L = 100 \Omega$ 0 < $V_{IN} \le 3.6 V$	_	600	_	MHz

- 1. Refer to Figure 9 on page 14.
- 2. Refer to Figure 10 on page 15.
- 3. Refer to Figure 8 on page 13.

Table 10. Switching characteristics ($T_A = 25$ °C, $V_{CC} = 3.3$ V ±10%)

Symbol	Parameter	Test condition		Unit		
Cymbol			Min.	Тур.	Max.	Offic
t _{PD}	Propagation delay	V _{CC} = 3 to 3.6 V	_	0.25	_	ns
t _{PZH} , t _{PZL}	Line enable time, SE to x to x0 or x to x1	V _{CC} = 3 to 3.6 V	0.5	6.5	15	ns
t _{PHZ} , t _{PLZ}	Line disable time, SE to x to x0 or x to x1	V _{CC} = 3 to 3.6 V	0.5	6.5	8.5	ns
t _{SK(O)}	Output skew between center port to any other port	V _{CC} = 3 to 3.6 V	-	0.1	0.2	Sns
t _{SK(P)}	Skew between opposite transition of the same output (t _{PHL} , t _{PLH})	V _{CC} = 3 to 3.6 V	-	0.1	0.2	ns

Table 11. ESD performance

Symbol	Test condition	1/6/	Value		Unit
Symbol	rest condition	Min.	Тур.	Max.	Offic
ESD	Contact discharge ⁽¹⁾ IEC61000-4-2	-	±8	-	kV
ESD	Human body model (MIL-STD-883)	-	±15	_	kV

^{1.} Refer to Figure 3: Diagram for suggested V_{CC} decoupling on page 10.

Electrical characteristics ST3DV520A

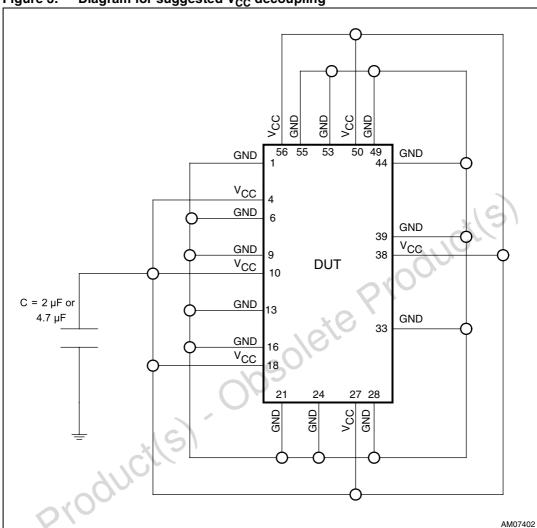


Figure 3. Diagram for suggested V_{CC} decoupling

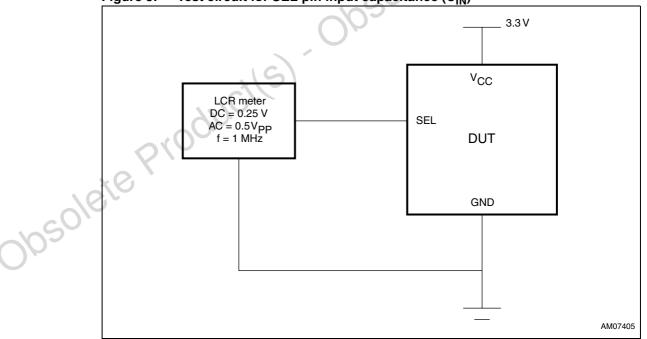
- 1. Applicable for system level ESD test.
- 2. 100 nF capacitors must be used as local bypass capacitors between the adjacent V_{CC} and GND pairs (total 7).

577

Test circuit for leakage current (I_{OFF}) 3.6 V v_{CC} A0 I_{OFF(SW)} Α Α1 FLOAT -3.6 V — SEL GND

Figure 4.

Test circuit for SEL pin input capacitance (C_{IN}) Figure 5.



AM07404

Electrical characteristics ST3DV520A

Figure 6. Test circuit for switch off capacitance (C_{OFF})

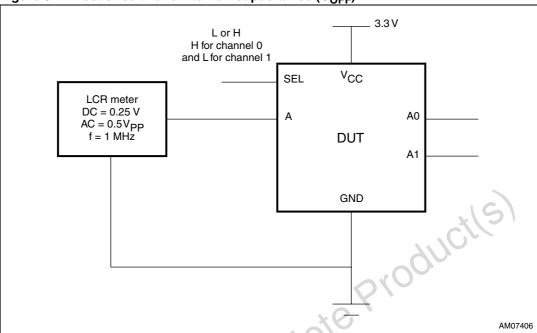
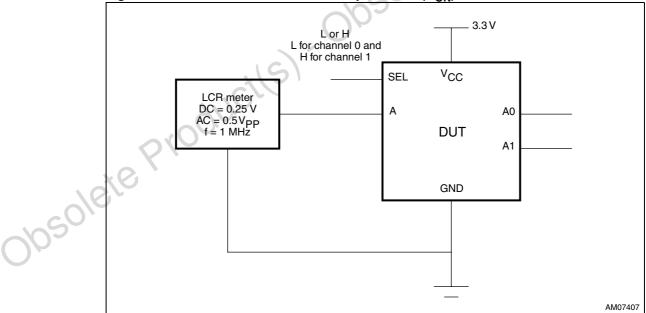


Figure 7. Test circuit for switch on capacitance (C_{ON})



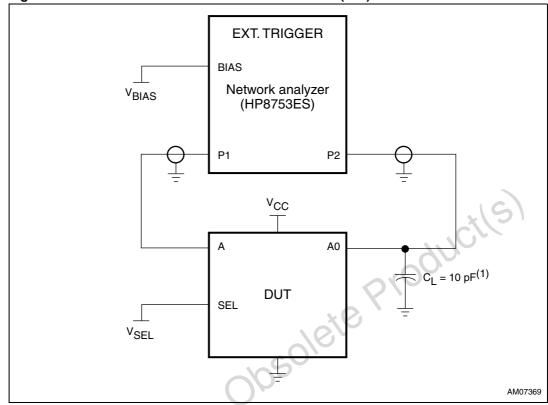


Figure 8. Test circuit for bandwidth measurement (BW)

1. C_L includes probe and jig capacitance.

Frequency response is measured at the output of the ON channel. For example, when $V_{\text{SEL}} = 0$ and A is the input, the output is measured at A0. All unused analog I/O ports are left open.

HP8753ES setup:

Average = 4

 $R_{BW} = 3 \text{ kHz}$

 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBm

Electrical characteristics ST3DV520A

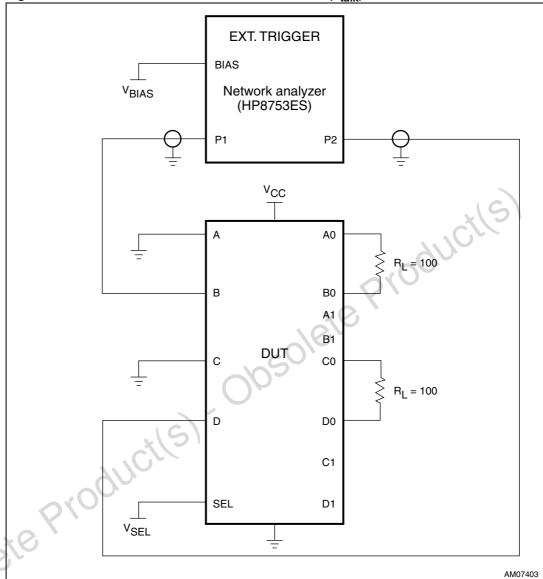


Figure 9. Test circuit for crosstalk measurement (x_{talk})

- 1. C_L includes probe and jig capacitance.
- 2. A 50 $\Omega\,\text{termination}$ resistor is needed to match the loading of the network analyzer.

Crosstalk is measured at the output of the non-adjacent ON channel. For example, when $V_{SEL} = 0$, and B is the input, the output is measured at D. All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup:

Average = 4

 $R_{BW} = 3 \text{ kHz}$

 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBm

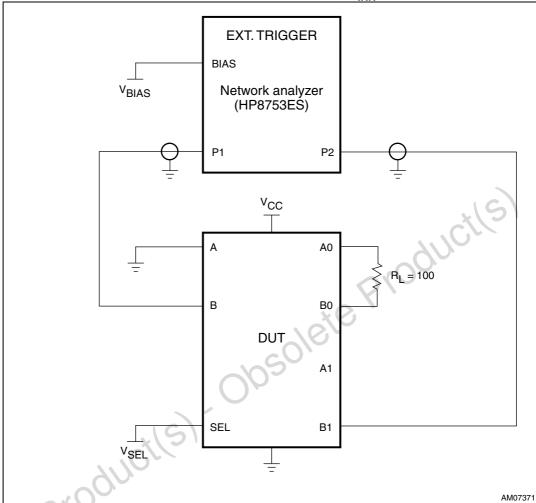


Figure 10. Test circuit for off isolation measurement (O_{IRR})

- 1. C_L includes probe and jig capacitance.
- 2. A 50 $\Omega\,\text{termination}$ resistor is needed to match the loading of the network analyzer.

Off isolation is measured at the output of the OFF channel. For example, when $V_{SEL} = 0$, and B is the input, the output is measured at B1. All unused analog input ports are connected to GND and output ports are left open.

HP8753ES setup:

Average = 4

 $R_{BW} = 3 \text{ kHz}$

 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBm

Package information ST3DV520A

5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

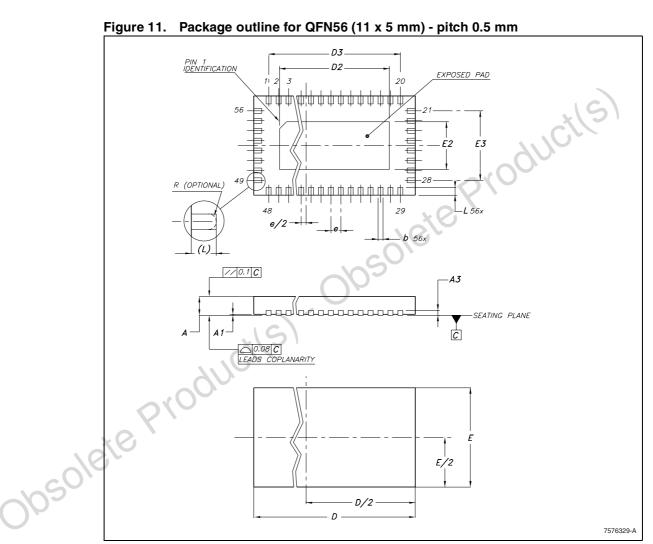
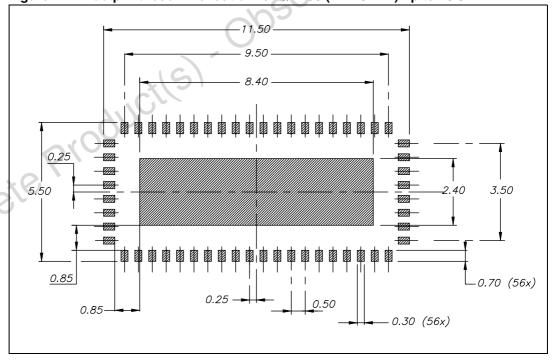


Table 12. Mechanical data for QFN56 (11 x 5 mm) - pitch 0.5 mm

Symbol	Millimeters		
	Min.	Тур.	Max.
А	0.70	0.75	0.80
A1	-	-	0.05
A3		0.20	-
b	0.20	0.25	0.30
D	10.90	11.00	11.10
D2	8.30	8.40	8.50
D3	_	9.50	.191
E	4.90	5.00	5.10
E2	2.30	2.40	2.50
E3	_	3.50	-
е	_	0.50	_
L	0.30	0.40	0.50

Figure 12. Footprint recommendation for QFN56 (11 x 5 mm) - pitch 0.5 mm



Package information ST3DV520A

Figure 13. Carrier tape information for QFN56 (11 x 5 mm) - pitch 0.5 mm Do ø1.55±0.05 2.0±0.1 (I) 4.0±0.1 (II) 0.30±0.05 E₁ 1.75±0.1 F D1 ø1.5m<u>in.</u> ≥ Q R0.3 Typical Р1 Αо SECTION Y-Y Measured from centreline of sprocket hole Αo 5.70 +/-0.1 to centreline of pocket. Во 11.90 +/-0.1 Cumulative tolerance of 10 sprocket holes is \pm 0.20 Κo 0.95 +/-0.1 Measured from centreline of sprocket hole to centreline of pocket. F 11.50 +/-0.1 P 1 Other material available. +/-0.1 8.00

0.3

24.00

Obsolete Product

7875978_K

ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED.

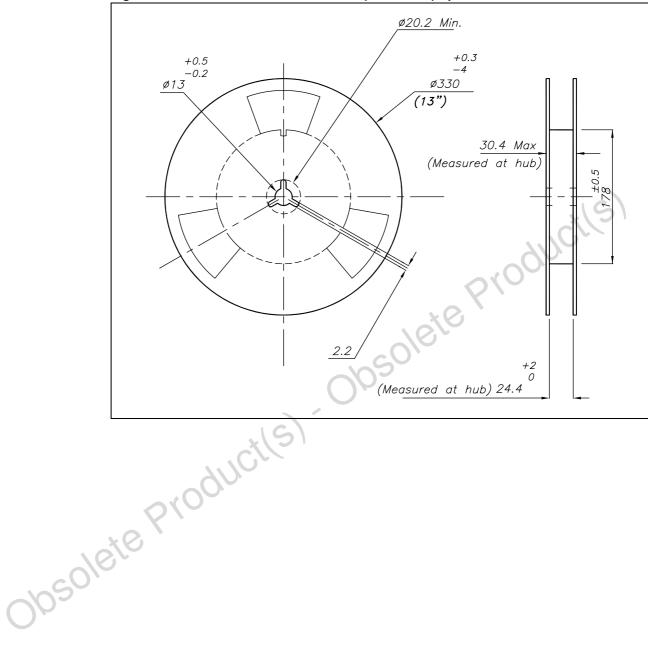


Figure 14. Reel information for QFN56 (11 x 5 mm) - pitch 0.5 mm

Revision history ST3DV520A

6 Revision history

Table 13. Document revision history

	Revision	Changes
11-Dec-2009	1	Initial release.
07-Apr-2010	2	Corrected circuit drawing errors in <i>Figure 2: Input equivalent circuit</i> . Modified text in the Description on page 1.
11-Jan-2011	3	Document reformatted, replaced V _{DD} by V _{CC} in <i>Figure 1</i> , <i>Table 2</i> , <i>Figure 3</i> , to <i>Figure 10</i> , moved notes below <i>Figure 8</i> to <i>Figure 10</i> , corrected typo in <i>Table 5</i> to <i>Table 7</i> , <i>Table 9</i> , <i>Figure 3</i> to <i>Figure 10</i> .
17-Jan-2013	4	Updated <i>Figure 1</i> (added numbers to pins) and <i>Table 2</i> (updated order of pins). Added cross-references in <i>Section 3</i> . Minor modifications throughout document.
ie Pro	ducil	s) Obsolete Pi

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

